NSN 5961-01-295-8538



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-295-8538 **Inclosure Material:** Glass or metal or ceramic **Overall Length:** 0.930 inches **Terminal Length:** 0.165 inches **Overall Height:** 0.192 inches **Overall Width:** 0.485 inches **Function For Which Designed:** Transient suppressor **Component Name And Quantity:** 15 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 6.0 breakdown voltage, instantaneous all semiconductor device diode and 5.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 300.00 microamperes forward current, average outside diameter all semiconductor device photo and 12.00 amperes all primaries universal all semiconductor device photo **Power Rating Per Characteristic:** 0.25 watts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

Demilitarization: Yes - demil/mli